

Digital Driver



Features

- High output voltage 12 V
- High gain 35 dB
- High SNR
- Single voltage power supply

Applications

- LiNbO₃ & InP modulators
- 10 Gbps DPSK
- 2×10 Gbps (D)QPSK
- Research & Development

Options

- Heat-sink
- Alternative RF connectors

The DR-DG-10-HO is a driver module optimized for digital applications requiring an upper operation voltage at 10 Gbps - 12.5 Gbps. It exhibits 12.5 V_{pp} output volatge and 35 dB gain up to 7 GHz.

The DR-DG-10-HO module is especially useful for driving $LiNb0_3$ modulators with 10 Gbps DPSK and 2 x 10 Gbps (D)QPSK modulation formats.

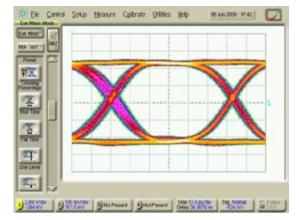
It is also a key device for multi-level modulation formats and for driving phase modulators. It is operated from a single power supply voltage for safety and ease of use and offers output voltage control. The DR-DG-10-HO comes with SMA type RF connectors (female in, male out) and with an optionnal heat sink. It is a non-inverting and single ended amplifier.

Performance Highlights

Parameter	Min	Тур	Max	Unit
Cut-off frequencies	80 k	-	7 G	Hz
Output Voltage	-	12.5	-	V
Gain	-	35	-	dB
Saturated Power	26	-	-	dBm
Added Jitter	-	1.75	-	ps
Rise / Fall Times	-	24.5	-	ps

Measurements for V_{bias} = 12 V, V_{amp} = 1.2 V, I_{bias} = 420 mA

12.5 Gbps Output Response





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DC Electrical Characteristics

Parameter	Symbol	Min	Тур	Мах	Unit
Supply voltage (fixed)	V_{bias}	-	12	-	V
Current consumption	I _{bias}	-	0.420	-	А
Gain control voltage	V_{amp}	0	1.4	-	V

Electrical Characteristics

Conditions: $V_{in} = 0.5 V_{pp}$, $T_{amb} = 25 \text{ °C}$, 50 Ω system

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Lower frequency	$f_{_{3dB}}$, lower	-3 dB point	-	-	80	kHz
Upper frequency	f _{3dB} , upper	-3 dB point	-	7	-	GHz
Gain	S ₂₁	Small signal	-	35	-	dB
Gain ripple	-	< 18 GHz	-	±1.5	-	dB
Input return loss	S ₁₁	10 MHz < f < 10 GHz	-	-10	-	dB
Output return loss	S ₂₂	10 MHz < f < 10 GHz	-	-10	-	dB
Output voltage	V _{out}	V _{in} = 0.5 V _{pp} @ 10.7 Gbps	-	12	-	V _{pp}
Rise time / Fall time	t _r / t _r	20 % - 80 %	-	24.5 / 24.5	-	ps
Added jitter	J _{RMS}	$J_{RMS} = \sqrt{J_{RMS-total}^2 - J_{RMS-source}^2}$	-	1.9	-	ps
Power dissipation	Р	$V_{out} = 12 V_{pp}$	-	5	-	W

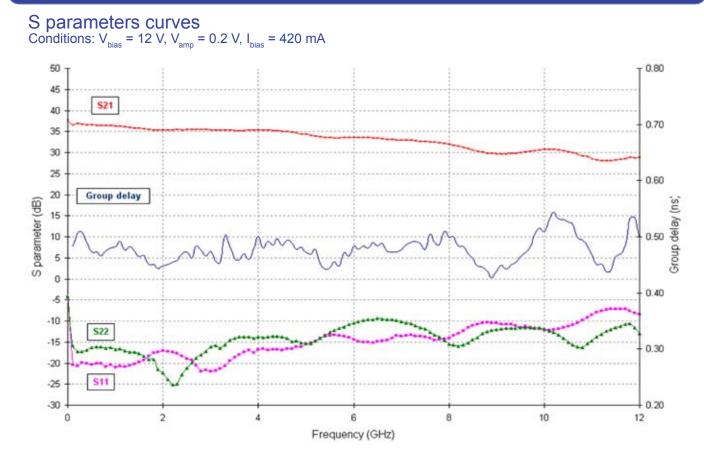
Absolute Maximum Ratings

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. These are absolute stress ratings only. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of the data sheet. Exposure to absolute maximum ratings for extended periods can adversely affect device reliability.

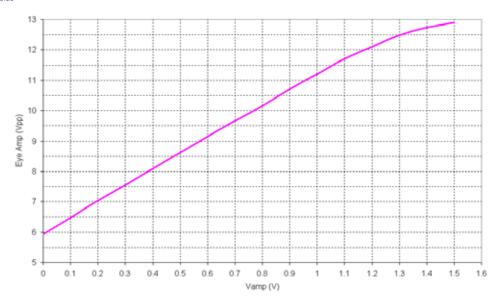
Parameter	Symbol	Min	Мах	Unit
RF input voltage	V _{in}	-	1.5	V _{pp}
Power supply voltage	V _{bias}	11.5	13	V
DC current	l _{bias}	-	0.45	А
Gain control voltage	V _{amp}	0	2	V
Power dissipation	P _{diss}	-	9.8	W
Temperature of operation	T _{op}	-5	+50	°C



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Typical output voltage amplitude vs gain control V_{amp} tuning Conditions: $V_{bias} = 12 \text{ V}$



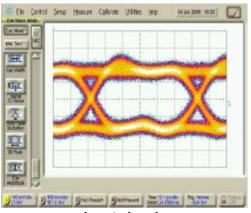


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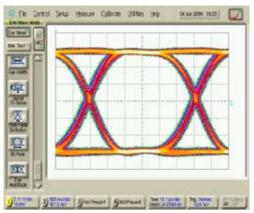
Eye Diagrams

10.709 Gbps data rate

Conditions: Ratio $\frac{1}{2}$, Pattern 2³¹-1 V_{bias} = 12 V, V_{amp} = 1.2 V, I_{bias} = 420 mA



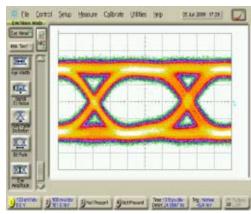
Input signal Genrated by Anritsu MP1758A Eye amplitude = 0.44 V, Rise time = 17.4 ps Jitter RMS = 2.14 ps, SNR = 8.1



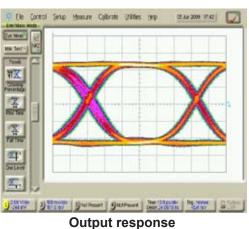
Output response Measured using Agilent 86100B with two 50 GHz 8348A channels module, and without precision time-base module Eye amplitude = 12.1 V, Rise time = 24.8 ps Jitter RMS = 1.67 ps, SNR = 43.5

12.5 Gbps data rate

Conditions: Ratio $\frac{1}{2}$, Pattern 2³¹-1 V_{bias} = 12 V, V_{amo} = 1.2 V, I_{bias} = 420 mA



Input signal Generated with a NEL MOF15A 2:1 selector Eye amplitude = 0.49 V, Rise time = 23 ps Jitter RMS = 2.24 ps, SNR = 8.8

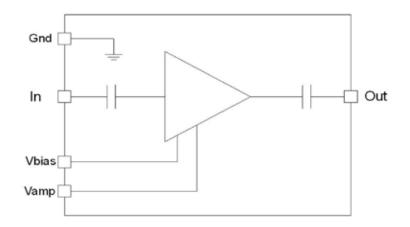


Measured using Agilent 86100B with two 50 GHz 8348A channels module, and without precision time-base module Eye amplitude = 12.1 V, Rise time = 25.3 ps Jitter RMS = 2.5 ps, SNR = 32.77



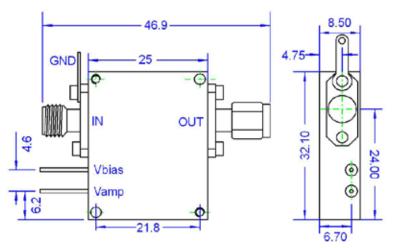
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Electrical Schematic Diagram



Mechanical diagram and pinout

All measurements in mm



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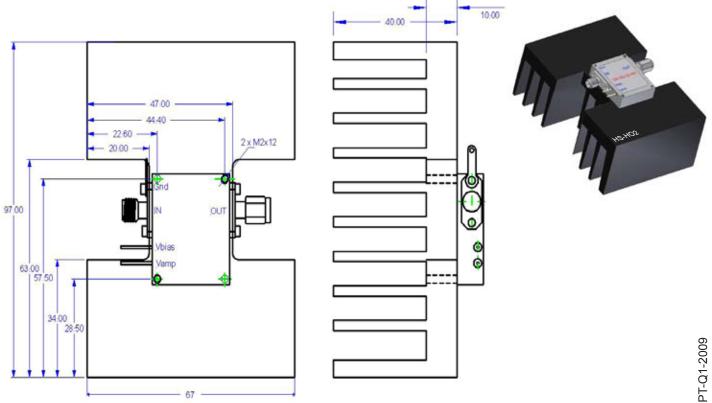
The heatsinking of the module is necessary. It's user responsability to use an adequate heatsink. Refer to page 6 for Photline Technologies recommended heatsink.

PIN	Function	Operational Notes
IN	RF In	SMA-connector female
OUT	RF Out	SMA-connector male
V _{bias}	Power supply voltage	Set at typical operating specification
V _{amp}	Output voltage amplitude adjustment	Adjust for gain control tuning



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Mechanical diagram and pinout with HS-HO2 heatsink All measurements in mm



V1, PT-Q1-2009

ABOUT US

Photline Technologies is a provider of Fiber Optics Modulation Solutions based on the company LiNb03 modulators and high-speed electronics modules. Photline Technologies offers high speed and high data rate modulation solutions for the telecommunication industry and the defense, aerospace, instruments and sensors markets. The products offered by the company include : comprehensive range of intensity and phase modulators (800 nm, 1060 nm, 1300 nm, 1550 nm), RF drivers and modules, transmitters and modulation units.

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